

# R1LV0108E Series

# 1Mb Advanced LPSRAM (128k word x 8bit)

R10DS0271EJ0200 Rev.2.00 2019.10.29

### **Description**

The R1LV0108E Series is a family of low voltage 1-Mbit static RAMs organized as 131,072-word by 8-bit, fabricated by Renesas's high-performance 0.15um CMOS and TFT technologies. The R1LV0108E Series has realized higher density, higher performance and low power consumption. The R1LV0108E Series is suitable for memory applications where a simple interfacing, battery operating and battery backup are the important design objectives. It has been packaged in 32-pin SOP, 32-pin TSOP and 32-pin sTSOP.

#### **Features**

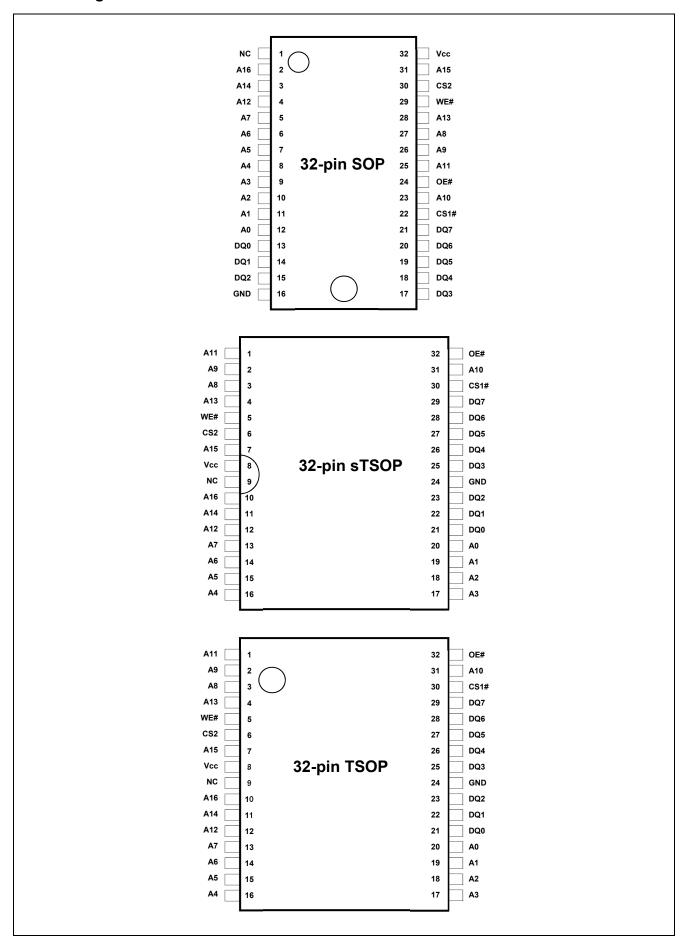
- Single 2.7V~3.6V power supply
- Small stand-by current: 0.6µA (3.0V, typical)
- No clocks, No refresh
- All inputs and outputs are TTL compatible.
- Easy memory expansion by CS1# and CS2
- Common Data I/O
- Three-state outputs: OR-tie Capability
- OE# prevents data contention on the I/O bus

### **Ordering Information**

Orderable part name	Access time	Temperature range	Package	Shipping container
R1LV0108ESN-5SI#B*			525-mil 32-pin	Tube (Magazine)
R1LV0108ESN-5SI#S*			plastic SOP	Embossed tape
R1LV0108ESA-5SI#B*	55 ns	-40 ∼ +85°C	8mm×13.4mm 32-pin	Tray
R1LV0108ESA-5SI#S*	55 HS	-40 ~ +65 C	plastic sTSOP	Embossed tape
R1LV0108ESF-5SI#B*			8mm×20mm 32-pin	Tray
R1LV0108ESF-5SI#S*			plastic TSOP	Embossed tape

Note 1. \* = Revision code for Assembly site change, etc. (\* = 0, 1, etc.)

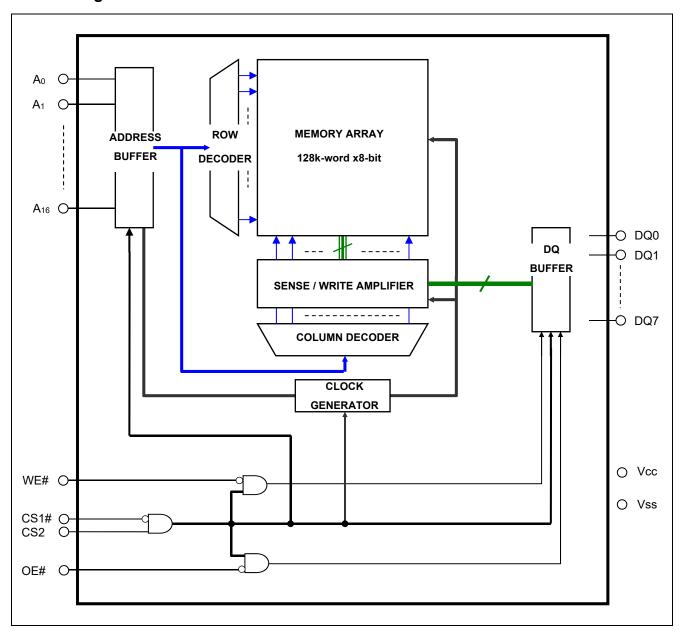
### **Pin Arrangement**



# **Pin Description**

Pin name	Function
Vcc	Power supply
Vss (GND)	Ground
A0 to A16	Address input
DQ0 to DQ7	Data input/output
CS1#	Chip select 1
CS2	Chip select 2
WE#	Write enable
OE#	Output enable
NC	Non connection

# **Block Diagram**



# **Operation Table**

CS1#	CS2	WE#	OE#	DQ0~7	Operation
Х	L	Х	Χ	High-Z	Stand-by
Н	Х	Х	Х	High-Z	Stand-by
L	Н	L	Х	Din	Write
L	Н	Н	L	Dout	Read
L	Н	Н	Н	High-Z	Output disable

Note 1. H:  $V_{IH}$  L: $V_{IL}$  X:  $V_{IH}$  or  $V_{IL}$ 

### **Absolute Maximum**

Parameter	Symbol	Value	unit
Power supply voltage relative to Vss	Vcc	-0.3 to +4.6	V
Terminal voltage on any pin relative to Vss	V <sub>T</sub>	-0.3*1 to Vcc+0.3*2	V
Power dissipation	PT	0.7	W
Operation temperature	Topr	-40 to +85	°C
Storage temperature range	Tstg	-65 to 150	°C
Storage temperature range under bias	Tbias	-40 to +85	°C

Note 1. –3.0V for pulse ≤ 30ns (full width at half maximum)

<sup>2.</sup> Maximum voltage is +4.6V.

# **DC Operating Conditions**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Note
Supply voltage	Vcc	2.7	3.0	3.6	V	
	Vss	0	0	0	V	
Input high voltage	V <sub>IH</sub>	2.0	-	Vcc+0.3	V	
Input low voltage	VIL	-0.3	-	0.6	V	1
Ambient temperature range	Та	-40	-	+85	°C	

Note 1. -3.0V for pulse  $\leq 30$ ns (full width at half maximum)

#### **DC Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions		
Input leakage current		-	-	1	μΑ	Vin = Vss t	o Vcc	
Output leakage current	<b>I</b> LO	-	-	1	μА	CS1# =V <sub>IH</sub> OE# =V <sub>IH</sub> , VI/O =Vss	or CS2 =V <sub>IL</sub> or to Vcc	
Average operating current	Icc <sub>1</sub>	-	15	25	mA		duty =100%, II/O = 0mA, CS2 =V <sub>IH</sub> , Others = V <sub>IH</sub> /V <sub>IL</sub>	
	Icc2	-	2	5	mA	CS1# ≤ 0.2	s, duty =100%, II/O = 0mA, 2V, CS2 ≥ Vcc-0.2V, 0.2V, V <sub>IL</sub> ≤ 0.2V	
Standby current	IsB	-	-	0.33	mA	"CS2 =V <sub>IL</sub> " "CS2 = V <sub>IH</sub> Others = V	and CS1# =V <sub>IH</sub> ",	
Standby current		-	0.6*1	2	μΑ	~+25°C	Vin = Vss to Vcc,	
	I <sub>SB1</sub>	-	-	3	μΑ	~+40°C	(1) CS2 ≤ 0.2V or (2) CS1#≥ Vcc-0.2V,	
	ISB1	-	-	8	μА	~+70°C	CS2 ≥ Vcc-0.2V	
		-	-	10	μА	~+85°C		
Output high voltage	Vон	2.4	-	-	V	I <sub>OH</sub> = -0.5m	nA	
	V <sub>OH2</sub>	Vcc - 0.5	-		V	Іон = -0.05	mA	
Output low voltage	V <sub>OL</sub>	_	-	0.4	V	I <sub>OL</sub> = 2mA		

Note 1. Typical parameter indicates the value for the center of distribution at 3.0V (Ta= 25°C), and not 100% tested.

# Capacitance

 $(Vcc = 2.7V \sim 3.6V, f = 1MHz, Ta = -40 \sim +85^{\circ}C)$ 

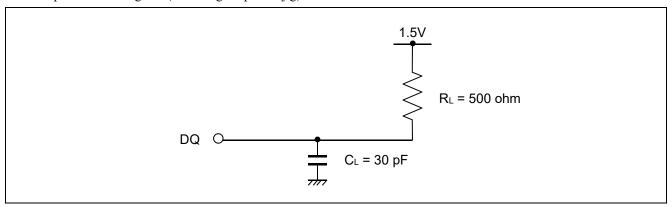
			•			·	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions	Note
Input capacitance	C in	-	-	8	pF	Vin =0V	1
Input / output capacitance	C 1/O	-	-	10	pF	VI/O =0V	1

Note 1. This parameter is sampled and not 100% tested.

#### **AC Characteristics**

Test Conditions (Vcc =  $2.7V \sim 3.6V$ , Ta =  $-40 \sim +85$ °C)

- Input pulse levels: VIL = 0.4V, VIH = 2.2V
- Input rise and fall time: 5ns
- Input and output timing reference level: 1.5V
- Output load: See figures (Including scope and jig)



#### **Read Cycle**

Parameter	Symbol	Min.	Max.	Unit	Note
Read cycle time	t <sub>RC</sub>	55	ı	ns	
Address access time	t <sub>AA</sub>	1	55	ns	
Chin colort aggest time	t <sub>ACS1</sub>	1	55	ns	
Chip select access time	t <sub>ACS2</sub>	-	55	ns	
Output enable to output valid	toE	1	30	ns	
Output hold from address change	tон	5	1	ns	
Chin coloct to output in low 7	t <sub>CLZ1</sub>	5	•	ns	2,3
Chip select to output in low-Z	t <sub>CLZ2</sub>	5	1	ns	2,3
Output enable to output in low-Z	toLZ	5	1	ns	2,3
Chin deceled to sutput in high 7	t <sub>CHZ1</sub>	0	20	ns	1,2,3
Chip deselect to output in high-Z	t <sub>CHZ2</sub>	0	20	ns	1,2,3
Output disable to output in high-Z	tonz	0	20	ns	1,2,3

#### **Write Cycle**

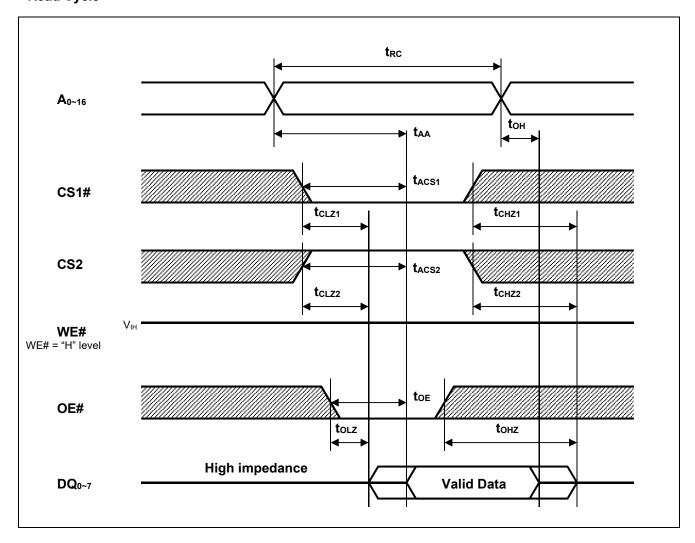
Parameter	Symbol	Min.	Max.	Unit	Note
Write cycle time	twc	55	-	ns	
Address valid to end of write	t <sub>AW</sub>	50	-	ns	
Chip select to end of write	tcw	50	-	ns	5
Write pulse width	twp	45	-	ns	4
Address setup time	t <sub>AS</sub>	0	-	ns	6
Write recovery time	twR	0	-	ns	7
Data to write time overlap	t <sub>DW</sub>	25	-	ns	
Data hold from write time	t <sub>DH</sub>	0	-	ns	
Output enable from end of write	tow	5	-	ns	2
Output disable to output in high-Z	tonz	0	20	ns	1,2
Write to output in high-Z	twnz	0	20	ns	1,2

#### Note

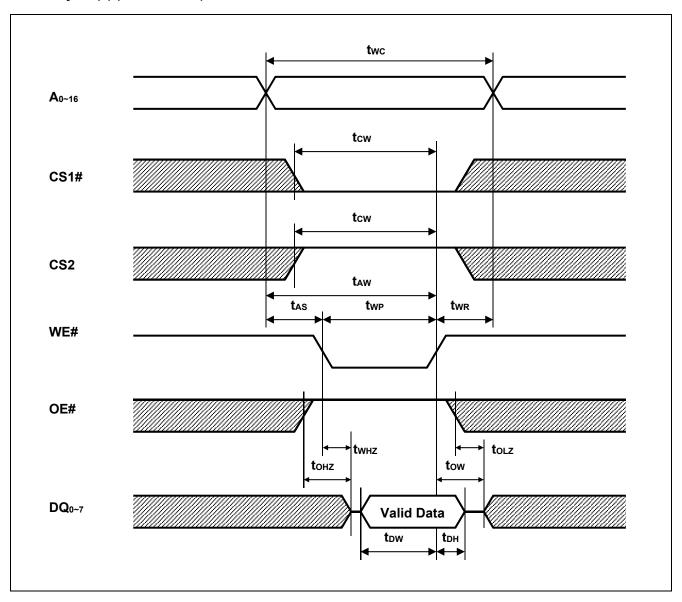
- 1. t<sub>CHZ</sub>, t<sub>OHZ</sub> and t<sub>WHZ</sub> are defined as the time at which the outputs achieve the open circuit conditions and are not referred to output voltage levels.
- 2. This parameter is sampled and not 100% tested.
- 3. At any given temperature and voltage condition,  $t_{HZ}$  max is less than  $t_{LZ}$  min both for a given device and from device to device.
- 4. A write occurs during the overlap of a low CS1#, a high CS2, a low WE#.
  - A write begins at the latest transition among CS1# going low, CS2 going high and WE# going low.
  - A write ends at the earliest transition among CS1# going high, CS2 going low and WE# going high. twp is measured from the beginning of write to the end of write.
- 5. t<sub>CW</sub> is measured from the later of CS1# going low or CS2 going high to end of write.
- 6. tas is measured the address valid to the beginning of write.
- 7. twR is measured from the earliest of CS1# or WE# going high or CS2 going low to the end of write cycle.
- 8. Don't apply inverted phase signal externally when DQ pin is output mode.

# **Timing Waveforms**

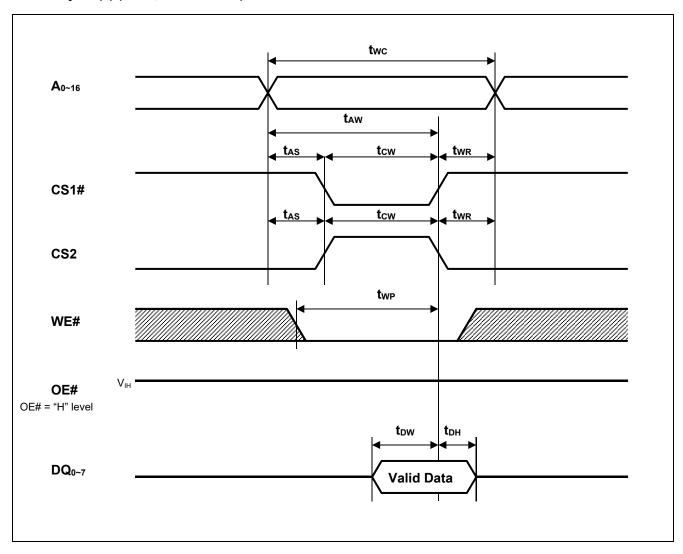
# Read Cycle



## Write Cycle (1) (WE# CLOCK)



### Write Cycle (2) (CS1#, CS2 CLOCK)



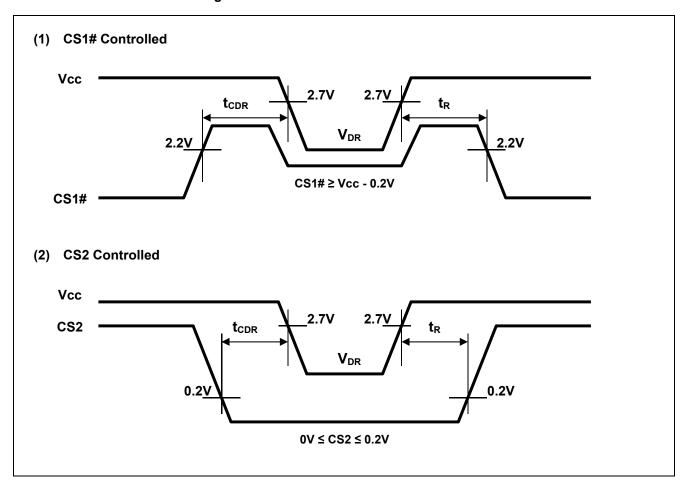
#### **Low Vcc Data Retention Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Unit		Test conditions*2		
V <sub>CC</sub> for data retention	V <sub>DR</sub>	2.0	-	3.6	V	Vin ≥ 0V, (1) 0V ≤ CS2 ≤ 0.2V or (2) CS1# ≥ Vcc-0.2V, CS2 ≥ Vcc-0.2V			
		-	0.6*1	2	μΑ	~+25°C	, Vcc=3.0V, Vin ≥ 0V,		
Data retention current	ICCDR	-	-	3	μΑ	~+40°C	(1) 0V ≤ CS2 ≤ 0.2V or		
		-	1	8	μΑ	~+70°C	(2) CS1# ≥ Vcc-0.2V, CS2 ≥ Vcc-0.2V		
		-	-	10	μΑ	~+85°C			
Chip deselect time to data retention	tcdr	0	-	-	ns	0			
Operation recovery time	t <sub>R</sub>	5	-	-	ms	See retention waveform.			

Note

- 1. Typical parameter indicates the value for the center of distribution at 3.0V (Ta= 25°C), and not 100% tested.
- 2. CS2 controls address buffer, WE# buffer, CS1# buffer, OE# buffer and Din buffer. If CS2 controls data retention mode, Vin levels (address, WE#, CS1#, OE#, DQ) can be in the high impedance state. If CS1# controls data retention mode, CS2 must be CS2 ≥ Vcc-0.2V or 0V ≤ CS2 ≤ 0.2V. The other input levels (address, WE#, OE#, DQ) can be in the high impedance state.

#### **Low Vcc Data Retention Timing Waveforms**



		Description					
Rev.	Date	Page	Page Summary				
1.00	2017.1.27	-	- First Edition issued				
2.00	2019.10.29	p.1	p.1 Revised orderable part name information.				

#### Notice

- 1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information
- Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples
- 3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others
- 4. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
- 5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the

Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment: industrial robots: etc.

"High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc. Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or

- 6. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified
- 7. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
- 8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations
- 9. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or
- 10. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
- 11. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.4.0-1 November 2017)



#### SALES OFFICES

## Renesas Electronics Corporation

http://www.renesas.com

Refer to "http://www.renesas.com/" for the latest and detailed information.

Renesas Electronics Corporation TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

Renesas Electronics America Inc. 1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A. Tel: +1-408-432-8888, Fax: +1-408-434-5351

Renesas Electronics Canada Limited

reet, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3

9251 Yonge Street, St Tel: +1-905-237-2004

Renesas Electronics Europe GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 101-T01, Floor 1, Building 7, Yard No. 7, 8th Street, Shangdi, Haidian District, Beijing 100085, China Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai 200333, China Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tel: +852-2265-6688, Fax: +852 2886-9022 Renesas Electronics Hong Kong Limited

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949 Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit No 3A-1 Level 3A Tower 8 UOA Business Park, No 1 Jalan Pengaturcara U1/51A, Seksyen U1, 40150 Shah Alam, Selangor, Malaysia Tel: +60-3-5022-1288, Fax: +60-3-5022-1290

Renesas Electronics India Pvt. Ltd. No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India Tel: +91-80-67208700

Renesas Electronics Korea Co., Ltd. 17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea Tel: +82-2-558-3737, Fax: +82-2-558-5338



OOO «ЛайфЭлектроникс" "LifeElectronics" LLC

ИНН 7805602321 КПП 780501001 P/C 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 3010181090000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

#### Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный) Email: org@lifeelectronics.ru